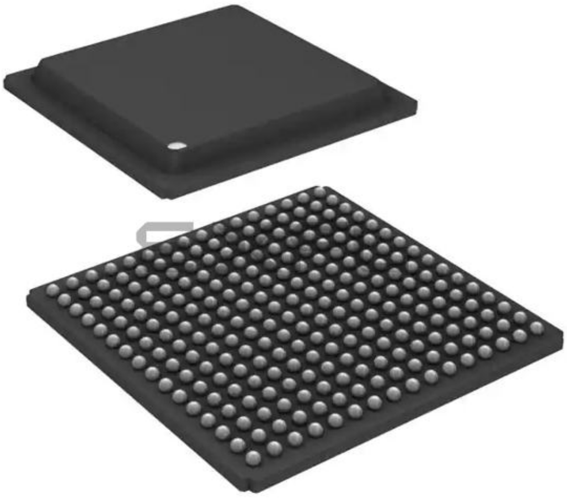

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	MPC8xx
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	50MHz
Co-Processors/DSP	Communications; CPM
RAM Controllers	DRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	3.3V
Operating Temperature	0°C ~ 95°C (TA)
Security Features	-
Package / Case	256-BGA
Supplier Device Package	256-PBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/xpc850dezt50bur2

  - Gate mode can enable/disable counting
  - Interrupt can be masked on reference match and event capture
- Interrupts
  - Eight external interrupt request (IRQ) lines
  - Twelve port pins with interrupt capability
  - Fifteen internal interrupt sources
  - Programmable priority among SCCs and USB
  - Programmable highest-priority request
- Single socket PCMCIA-ATA interface
  - Master (socket) interface, release 2.1 compliant
  - Single PCMCIA socket
  - Supports eight memory or I/O windows
- Communications processor module (CPM)
  - 32-bit, Harvard architecture, scalar RISC communications processor (CP)
  - Protocol-specific command sets (for example, GRACEFUL STOP TRANSMIT stops transmission after the current frame is finished or immediately if no frame is being sent and CLOSE RXBD closes the receive buffer descriptor)
  - Supports continuous mode transmission and reception on all serial channels
  - Up to 8 Kbytes of dual-port RAM
  - Twenty serial DMA (SDMA) channels for the serial controllers, including eight for the four USB endpoints
  - Three parallel I/O registers with open-drain capability
- Four independent baud-rate generators (BRGs)
  - Can be connected to any SCC, SMC, or USB
  - Allow changes during operation
  - Autobaud support option
- Two SCCs (serial communications controllers)
  - Ethernet/IEEE 802.3, supporting full 10-Mbps operation
  - HDLC/SDLC™ (all channels supported at 2 Mbps)
  - HDLC bus (implements an HDLC-based local area network (LAN))
  - Asynchronous HDLC to support PPP (point-to-point protocol)
  - AppleTalk®
  - Universal asynchronous receiver transmitter (UART)
  - Synchronous UART
  - Serial infrared (IrDA)
  - Totally transparent (bit streams)
  - Totally transparent (frame based with optional cyclic redundancy check (CRC))

- QUICC multichannel controller (QMC) microcode features
  - Up to 64 independent communication channels on a single SCC
  - Arbitrary mapping of 0–31 channels to any of 0–31 TDM time slots
  - Supports either transparent or HDLC protocols for each channel
  - Independent TxBDs/Rx and event/interrupt reporting for each channel
- One universal serial bus controller (USB)
  - Supports host controller and slave modes at 1.5 Mbps and 12 Mbps
- Two serial management controllers (SMCs)
  - UART
  - Transparent
  - General circuit interface (GCI) controller
  - Can be connected to the time-division-multiplexed (TDM) channel
- One serial peripheral interface (SPI)
  - Supports master and slave modes
  - Supports multimaster operation on the same bus
- One $I^2C^®$ (interprocessor-integrated circuit) port
  - Supports master and slave modes
  - Supports multimaster environment
- Time slot assigner
  - Allows SCCs and SMCs to run in multiplexed operation
  - Supports T1, CEPT, PCM highway, ISDN basic rate, ISDN primary rate, user-defined
  - 1- or 8-bit resolution
  - Allows independent transmit and receive routing, frame syncs, clocking
  - Allows dynamic changes
  - Can be internally connected to four serial channels (two SCCs and two SMCs)
- Low-power support
  - Full high: all units fully powered at high clock frequency
  - Full low: all units fully powered at low clock frequency
  - Doze: core functional units disabled except time base, decrementer, PLL, memory controller, real-time clock, and CPM in low-power standby
  - Sleep: all units disabled except real-time clock and periodic interrupt timer. PLL is active for fast wake-up
  - Deep sleep: all units disabled including PLL, except the real-time clock and periodic interrupt timer
  - Low-power stop: to provide lower power dissipation

4 Thermal Characteristics

Table 3 shows the thermal characteristics for the MPC850.

Table 3. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal resistance for BGA [1]	θ_{JA}	40 [2]	°C/W
	θ_{JA}	31 [3]	°C/W
	θ_{JA}	24 [4]	°C/W
Thermal Resistance for BGA (junction-to-case)	θ_{JC}	8	°C/W

1 For more information on the design of thermal vias on multilayer boards and BGA layout considerations in general, refer to AN-1231/D, *Plastic Ball Grid Array Application Note* available from your local Freescale sales office.

2 Assumes natural convection and a single layer board (no thermal vias).

3 Assumes natural convection, a multilayer board with thermal vias[4], 1 watt MPC850 dissipation, and a board temperature rise of 20°C above ambient.

4 Assumes natural convection, a multilayer board with thermal vias[4], 1 watt MPC850 dissipation, and a board temperature rise of 13°C above ambient.

$T_J = T_A + (P_D \bullet \theta_{JA})$

$P_D = (V_{DD} \bullet I_{DD}) + P_{I/O}$

where:

$P_{I/O}$ is the power dissipation on pins

Table 4 provides power dissipation information.

Table 4. Power Dissipation (P_D)

Characteristic	Frequency (MHz)	Typical [1]	Maximum [2]	Unit
Power Dissipation All Revisions (1:1) Mode	33	TBD	515	mW
	40	TBD	590	mW
	50	TBD	725	mW

1 Typical power dissipation is measured at 3.3V

2 Maximum power dissipation is measured at 3.65 V

Table 5 provides the DC electrical characteristics for the MPC850.

Table 5. DC Electrical Specifications

Characteristic	Symbol	Min	Max	Unit
Operating voltage at 40 MHz or less	VDDH, VDDL, KAPWR, VDDSYN	3.0	3.6	V
Operating voltage at 40 MHz or higher	VDDH, VDDL, KAPWR, VDDSYN	3.135	3.465	V
Input high voltage (address bus, data bus, EXTAL, EXTCLK, and all bus control/status signals)	VIH	2.0	3.6	V
Input high voltage (all general purpose I/O and peripheral pins)	VIH	2.0	5.5	V

Table 6. Bus Operation Timing [1] (continued)

Num	Characteristic	50 MHz		66 MHz		80 MHz		FFACT	Cap Load (default 50 pF)	Unit
		Min	Max	Min	Max	Min	Max			
B9	CLKOUT to A[6–31] RD/WR, BURST, D[0–31], DP[0–3], TSIZ[0–1], REG, RSV, AT[0–3], PTR high-Z	5.00	11.75	7.58	14.33	6.25	13.00	0.250	50.00	ns
B11	CLKOUT to TS, BB assertion	5.00	11.00	7.58	13.58	6.25	12.25	0.250	50.00	ns
B11a	CLKOUT to TA, BI assertion, (When driven by the memory controller or PCMCIA interface)	2.50	9.25	2.50	9.25	2.50	9.25	—	50.00	ns
B12	CLKOUT to TS, BB negation	5.00	11.75	7.58	14.33	6.25	13.00	0.250	50.00	ns
B12a	CLKOUT to TA, BI negation (when driven by the memory controller or PCMCIA interface)	2.50	11.00	2.50	11.00	2.50	11.00	—	50.00	ns
B13	CLKOUT to TS, BB high-Z	5.00	19.00	7.58	21.58	6.25	20.25	0.250	50.00	ns
B13a	CLKOUT to TA, BI high-Z, (when driven by the memory controller or PCMCIA interface)	2.50	15.00	2.50	15.00	2.50	15.00	—	50.00	ns
B14	CLKOUT to TEA assertion	2.50	10.00	2.50	10.00	2.50	10.00	—	50.00	ns
B15	CLKOUT to TEA high-Z	2.50	15.00	2.50	15.00	2.50	15.00	—	50.00	ns
B16	TA, BI valid to CLKOUT(setup time) [5]	9.75	—	9.75	—	9.75	—	—	50.00	ns
B16a	TEA, KR, RETRY, valid to CLKOUT (setup time) [5]	10.00	—	10.00	—	10.00	—	—	50.00	ns
B16b	BB, BG, BR valid to CLKOUT (setup time) [6]	8.50	—	8.50	—	8.50	—	—	50.00	ns
B17	CLKOUT to TA, TEA, BI, BB, BG, BR valid (Hold time).[5]	1.00	—	1.00	—	1.00	—	—	50.00	ns
B17a	CLKOUT to KR, RETRY, except TEA valid (hold time)	2.00	—	2.00	—	2.00	—	—	50.00	ns
B18	D[0–31], DP[0–3] valid to CLKOUT rising edge (setup time) [7]	6.00	—	6.00	—	6.00	—	—	50.00	ns
B19	CLKOUT rising edge to D[0–31], DP[0–3] valid (hold time) [7]	1.00	—	1.00	—	1.00	—	—	50.00	ns
B20	D[0–31], DP[0–3] valid to CLKOUT falling edge (setup time) [8]	4.00	—	4.00	—	4.00	—	—	50.00	ns
B21	CLKOUT falling edge to D[0–31], DP[0–3] valid (hold time) [8]	2.00	—	2.00	—	2.00	—	—	—	—

Table 6. Bus Operation Timing [1] (continued)

Num	Characteristic	50 MHz		66 MHz		80 MHz		FFACT	Cap Load (default 50 pF)	Unit
		Min	Max	Min	Max	Min	Max			
B22	CLKOUT rising edge to $\overline{\text{CS}}$ asserted GPCM ACS = 00	5.00	11.75	7.58	14.33	6.25	13.00	0.250	50.00	ns
B22a	CLKOUT falling edge to $\overline{\text{CS}}$ asserted GPCM ACS = 10, TRLX = 0,1	—	8.00	—	8.00	—	8.00	—	50.00	ns
B22b	CLKOUT falling edge to $\overline{\text{CS}}$ asserted GPCM ACS = 11, TRLX = 0, EBDF = 0	5.00	11.75	7.58	14.33	6.25	13.00	0.250	50.00	ns
B22c	CLKOUT falling edge to $\overline{\text{CS}}$ asserted GPCM ACS = 11, TRLX = 0, EBDF = 1	7.00	14.00	11.00	18.00	9.00	16.00	0.375	50.00	ns
B23	CLKOUT rising edge to $\overline{\text{CS}}$ negated GPCM read access, GPCM write access ACS = 00, TRLX = 0 & CSNT = 0	2.00	8.00	2.00	8.00	2.00	8.00	—	50.00	ns
B24	A[6–31] to $\overline{\text{CS}}$ asserted GPCM ACS = 10, TRLX = 0.	3.00	—	6.00	—	4.00	—	0.250	50.00	ns
B24a	A[6–31] to $\overline{\text{CS}}$ asserted GPCM ACS = 11, TRLX = 0	8.00	—	13.00	—	11.00	—	0.500	50.00	ns
B25	$\overline{\text{CLKOUT}}$ rising edge to $\overline{\text{OE}}$, $\overline{\text{WE[0–3]}}$ asserted	—	9.00	—	9.00	—	9.00	—	50.00	ns
B26	CLKOUT rising edge to $\overline{\text{OE}}$ negated	2.00	9.00	2.00	9.00	2.00	9.00	—	50.00	ns
B27	A[6–31] to $\overline{\text{CS}}$ asserted GPCM ACS = 10, TRLX = 1	23.00	—	36.00	—	29.00	—	1.250	50.00	ns
B27a	A[6–31] to $\overline{\text{CS}}$ asserted GPCM ACS = 11, TRLX = 1	28.00	—	43.00	—	36.00	—	1.500	50.00	ns
B28	$\overline{\text{CLKOUT}}$ rising edge to $\overline{\text{WE[0–3]}}$ negated GPCM write access CSNT = 0	—	9.00	—	9.00	—	9.00	—	50.00	ns
B28a	$\overline{\text{CLKOUT}}$ falling edge to $\overline{\text{WE[0–3]}}$ negated GPCM write access TRLX = 0,1 CSNT = 1, EBDF = 0	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B28b	CLKOUT falling edge to $\overline{\text{CS}}$ negated GPCM write access TRLX = 0,1 CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	—	12.00	—	14.00	—	13.00	0.250	50.00	ns

Figure 13 through Figure 15 provide the timing for the external bus write controlled by various GPCM factors.

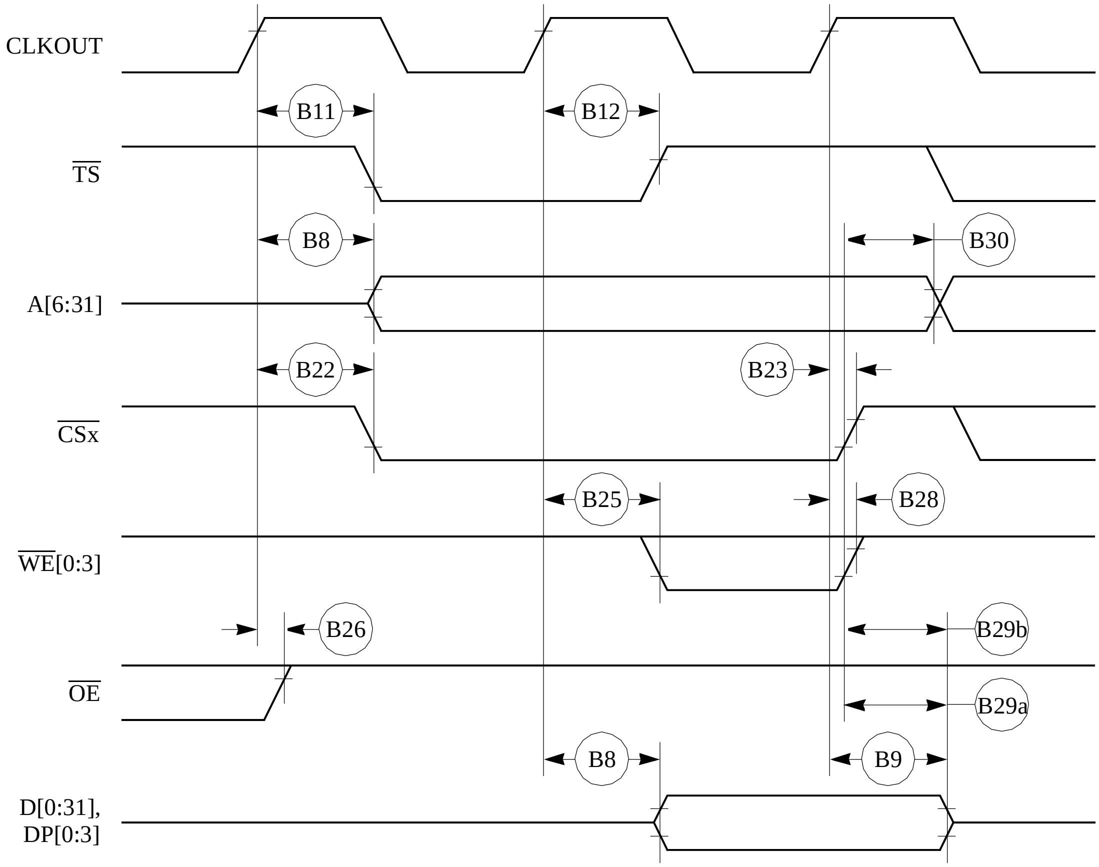


Figure 13. External Bus Write Timing (GPCM Controlled—TRLX = 0, CSNT = 0)

Figure 16 provides the timing for the external bus controlled by the UPM.

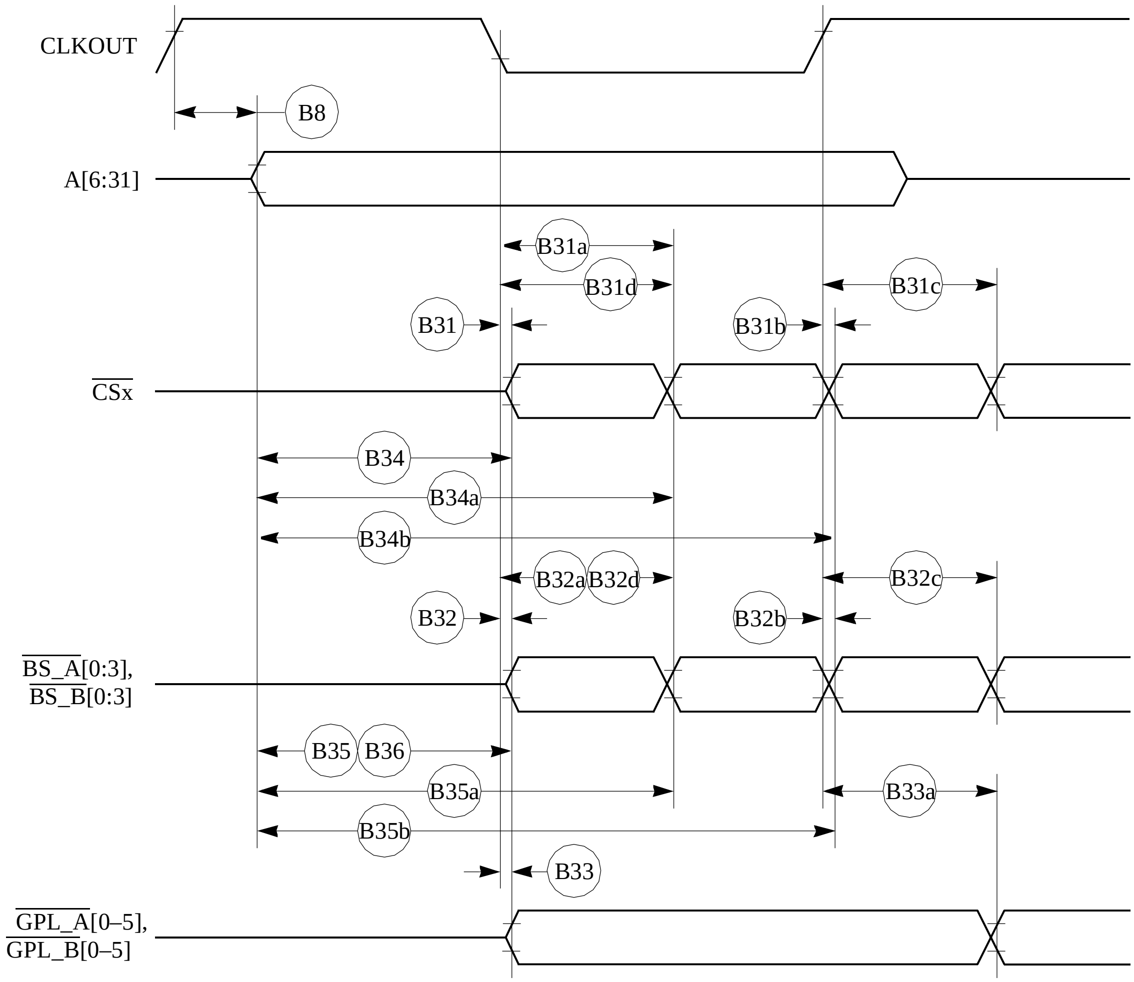


Figure 16. External Bus Timing (UPM Controlled Signals)

Figure 19 provides the timing for the synchronous external master access controlled by the GPCM.

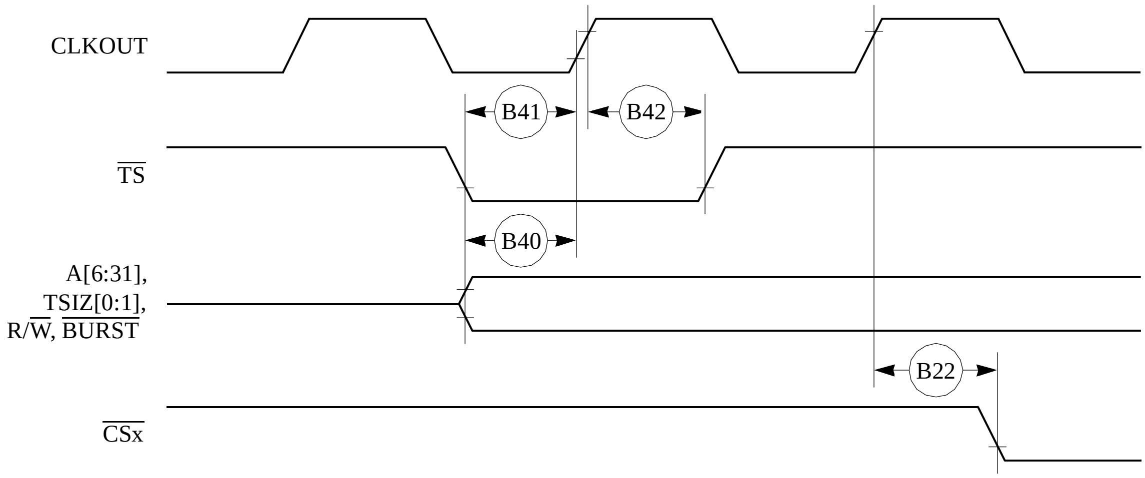


Figure 19. Synchronous External Master Access Timing (GPCM Handled ACS = 00)

Figure 20 provides the timing for the asynchronous external master memory access controlled by the GPCM.

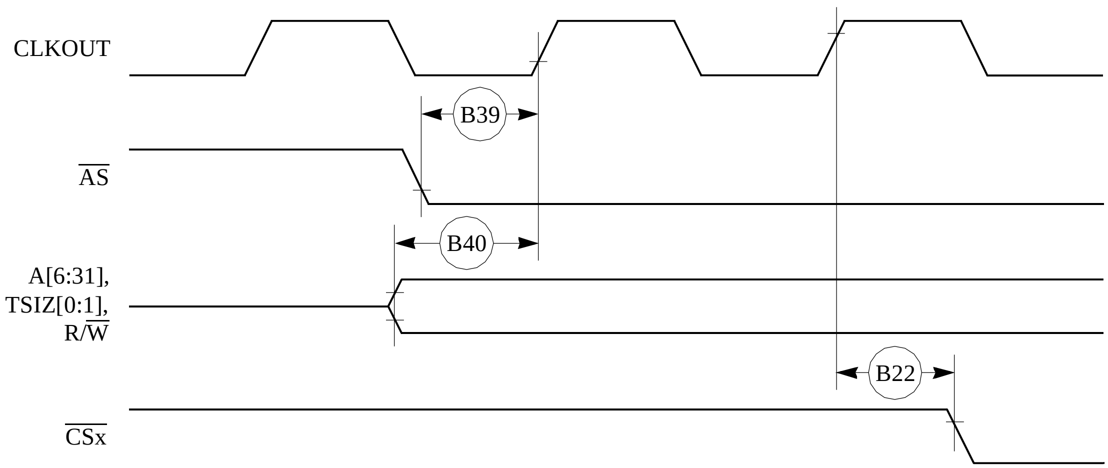


Figure 20. Asynchronous External Master Memory Access Timing (GPCM Controlled—ACS = 00)

Figure 21 provides the timing for the asynchronous external master control signals negation.

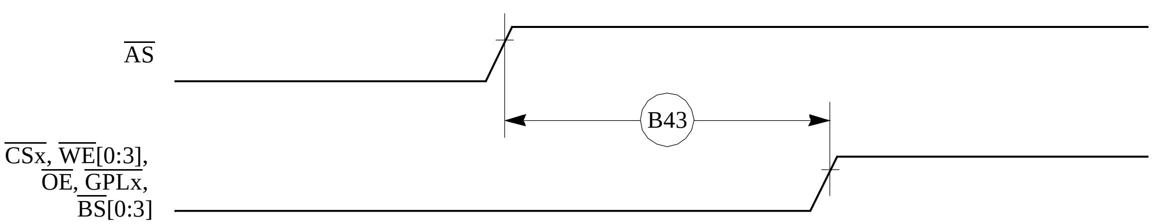


Figure 21. Asynchronous External Master—Control Signals Negation Timing

Table 8 shows the PCMCIA timing for the MPC850.

Table 8. PCMCIA Timing

Num	Characteristic	50MHz		66MHz		80 MHz		FFACTOR	Unit
		Min	Max	Min	Max	Min	Max		
P44	A[6–31], REG valid to PCMCIA strobe asserted. [1]	13.00	—	21.00	—	17.00	—	0.750	ns
P45	A[6–31], REG valid to ALE negation.[1]	18.00	—	28.00	—	23.00	—	1.000	ns
P46	CLKOUT to REG valid	5.00	13.00	8.00	16.00	6.00	14.00	0.250	ns
P47	CLKOUT to REG Invalid.	6.00	—	9.00	—	7.00	—	0.250	ns
P48	CLKOUT to CE1, CE2 asserted.	5.00	13.00	8.00	16.00	6.00	14.00	0.250	
P49	CLKOUT to CE1, CE2 negated.	5.00	13.00	8.00	16.00	6.00	14.00	0.250	ns
P50	CLKOUT to PCOE, IORD, PCWE, IOWR assert time.	—	11.00	—	11.00	—	11.00	—	ns
P51	CLKOUT to PCOE, IORD, PCWE, IOWR negate time.	2.00	11.00	2.00	11.00	2.00	11.00	—	ns
P52	CLKOUT to ALE assert time	5.00	13.00	8.00	16.00	6.00	14.00	0.250	ns
P53	CLKOUT to ALE negate time	—	13.00	—	16.00	—	14.00	0.250	ns
P54	PCWE, IOWR negated to D[0–31] invalid.[1]	3.00	—	6.00	—	4.00	—	0.250	ns
P55	WAIT_B valid to CLKOUT rising edge.[1]	8.00	—	8.00	—	8.00	—	—	ns
P56	CLKOUT rising edge to WAIT_B invalid.[1]	2.00	—	2.00	—	2.00	—	—	ns

[1] PSST = 1. Otherwise add PSST times cycle time.
PSHT = 0. Otherwise add PSHT times cycle time.

These synchronous timings define when the WAIT_B signal is detected in order to freeze (or relieve) the PCMCIA current cycle. The WAIT_B assertion will be effective only if it is detected 2 cycles before the PSL timer expiration. See PCMCIA Interface in the MPC850 PowerQUICC User's Manual.

Figure 25 provides the PCMCIA access cycle timing for the external bus write.

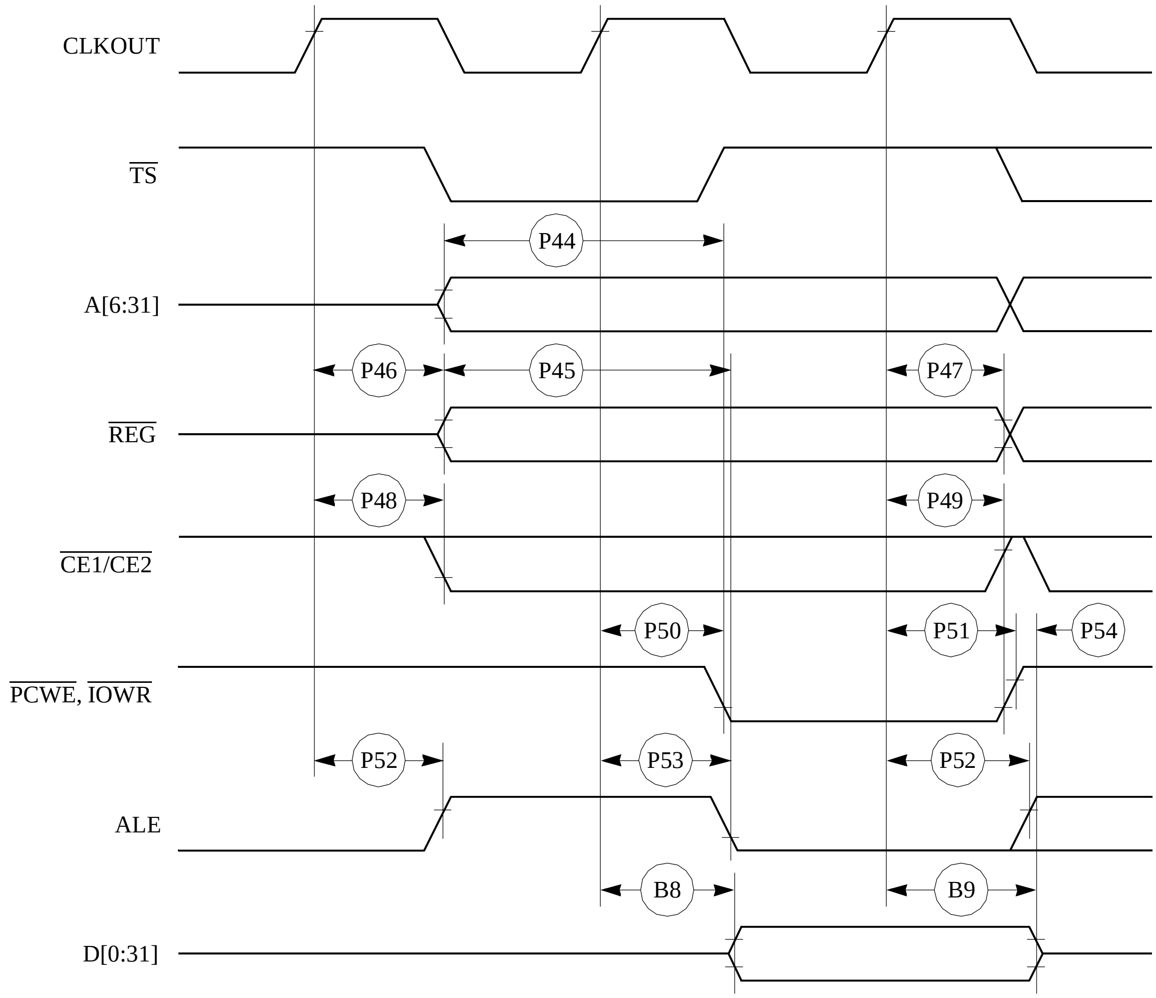


Figure 25. PCMCIA Access Cycles Timing External Bus Write

Figure 26 provides the PCMCIA WAIT signals detection timing.

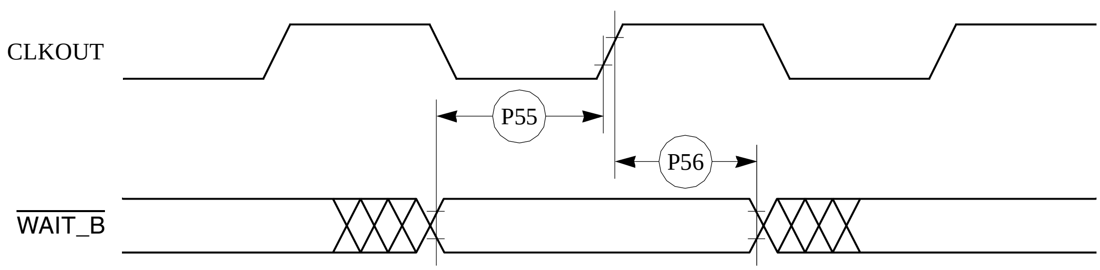


Figure 26. PCMCIA WAIT Signal Detection Timing

Table 11 shows the reset timing for the MPC850.

Table 11. Reset Timing

Num	Characteristic	50 MHz		66MHz		80 MHz		FFACTOR	Unit
		Min	Max	Min	Max	Min	Max		
R69	CLKOUT to HRESET high impedance	—	20.00	—	20.00	—	20.00	—	ns
R70	CLKOUT to SRESET high impedance	—	20.00	—	20.00	—	20.00	—	ns
R71	RSTCONF pulse width	340.00	—	515.00	—	425.00	—	17.000	ns
R72		—	—	—	—	—	—	—	
R73	Configuration data to HRESET rising edge set up time	350.00	—	505.00	—	425.00	—	15.000	ns
R74	Configuration data to RSTCONF rising edge set up time	350.00	—	350.00	—	350.00	—	—	ns
R75	Configuration data hold time after RSTCONF negation	0.00	—	0.00	—	0.00	—	—	ns
R76	Configuration data hold time after HRESET negation	0.00	—	0.00	—	0.00	—	—	ns
R77	HRESET and RSTCONF asserted to data out drive	—	25.00	—	25.00	—	25.00	—	ns
R78	RSTCONF negated to data out high impedance.	—	25.00	—	25.00	—	25.00	—	ns
R79	CLKOUT of last rising edge before chip tristates HRESET to data out high impedance.	—	25.00	—	25.00	—	25.00	—	ns
R80	DSDI, DSCK set up	60.00	—	90.00	—	75.00	—	3.000	ns
R81	DSDI, DSCK hold time	0.00	—	0.00	—	0.00	—	—	ns
R82	SRESET negated to CLKOUT rising edge for DSDI and DSCK sample	160.00	—	242.00	—	200.00	—	8.000	ns

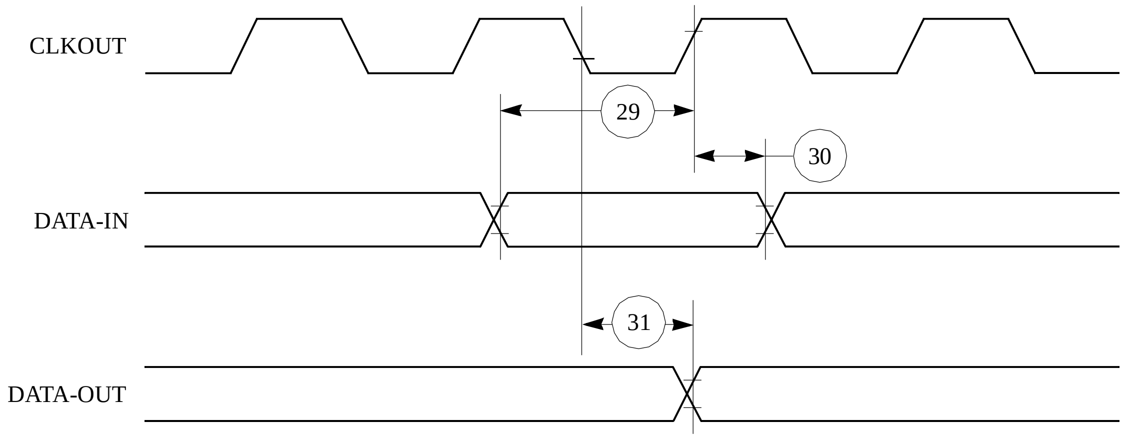


Figure 38. Parallel I/O Data-In/Data-Out Timing Diagram

8.2 IDMA Controller AC Electrical Specifications

Table 14 provides the IDMA controller timings as shown in Figure 39 to Figure 42.

Table 14. IDMA Controller Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
40	$\overline{\text{DREQ}}$ setup time to clock high	7.00	—	ns
41	$\overline{\text{DREQ}}$ hold time from clock high	3.00	—	ns
42	$\overline{\text{SDACK}}$ assertion delay from clock high	—	12.00	ns
43	$\overline{\text{SDACK}}$ negation delay from clock low	—	12.00	ns
44	$\overline{\text{SDACK}}$ negation delay from $\overline{\text{TA}}$ low	—	20.00	ns
45	$\overline{\text{SDACK}}$ negation delay from clock high	—	15.00	ns
46	$\overline{\text{TA}}$ assertion to falling edge of the clock setup time (applies to external $\overline{\text{TA}}$)	7.00	—	ns

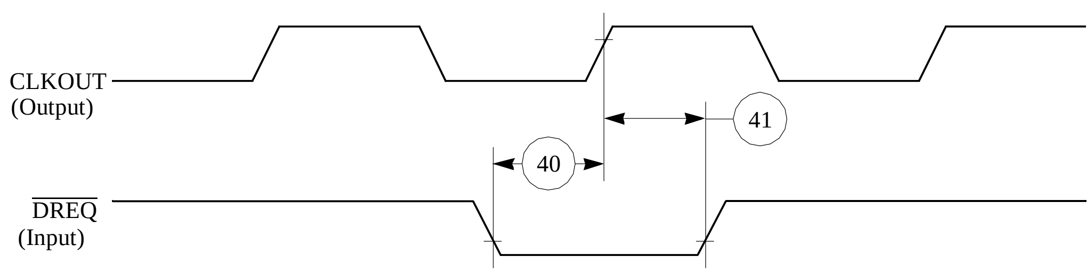


Figure 39. IDMA External Requests Timing Diagram

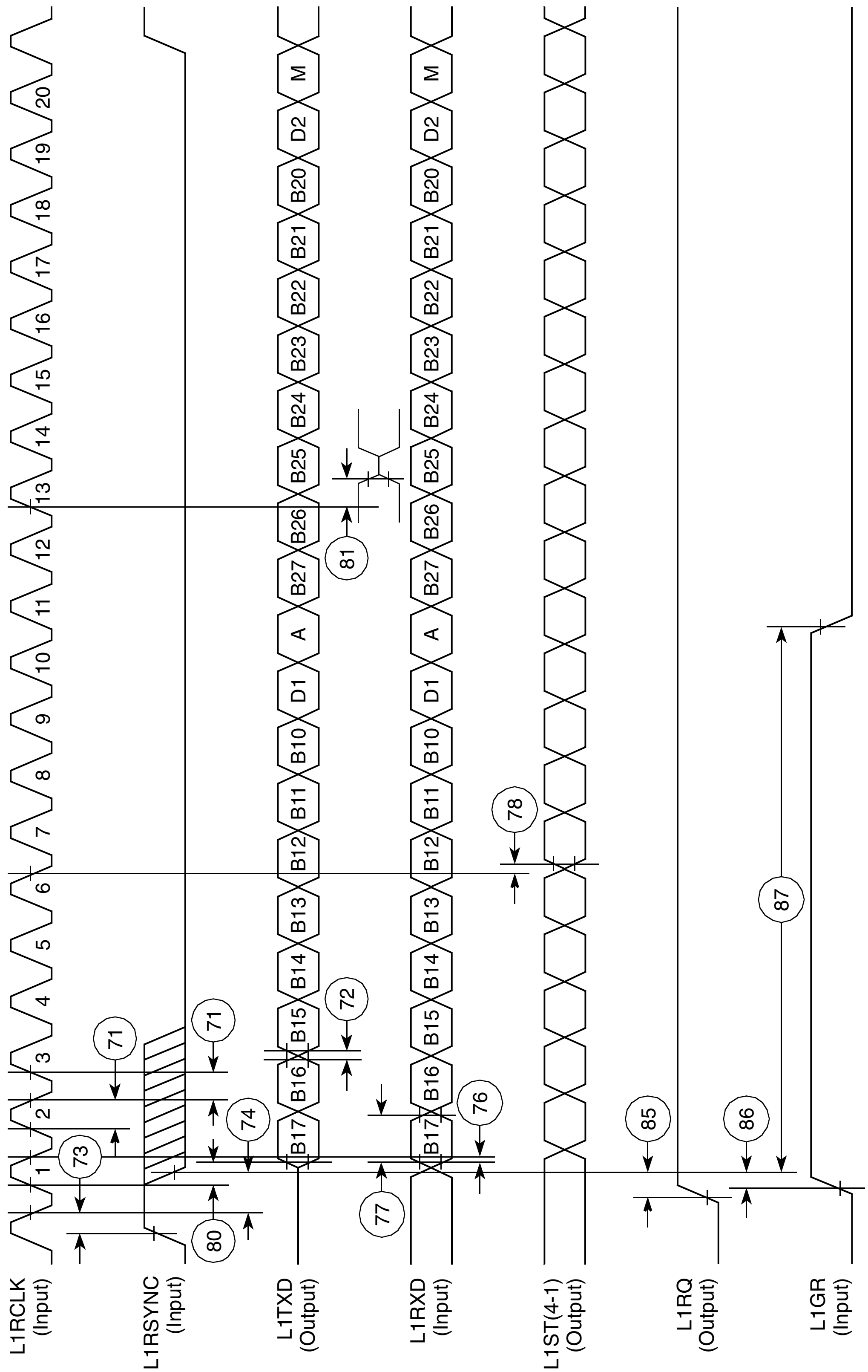


Figure 49. IDL Timing

8.6 SCC in NMSI Mode Electrical Specifications

Table 18 provides the NMSI external clock timing.

Table 18. NMSI External Clock Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
100	RCLKx and TCLKx frequency [1] (x = 2, 3 for all specs in this table)	1/SYNCCLK	—	ns
101	RCLKx and TCLKx width low	1/SYNCCLK +5	—	ns
102	RCLKx and TCLKx rise/fall time	—	15.00	ns
103	TXDx active delay (from TCLKx falling edge)	0.00	50.00	ns
104	$\overline{\text{RTSx}}$ active/inactive delay (from TCLKx falling edge)	0.00	50.00	ns
105	$\overline{\text{CTSx}}$ setup time to TCLKx rising edge	5.00	—	ns
106	RXDx setup time to RCLKx rising edge	5.00	—	ns
107	RXDx hold time from RCLKx rising edge [2]	5.00	—	ns
108	$\overline{\text{CDx}}$ setup time to RCLKx rising edge	5.00	—	ns

1 The ratios SyncCLK/RCLKx and SyncCLK/TCLKx must be greater than or equal to 2.25/1.

2 Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signal.

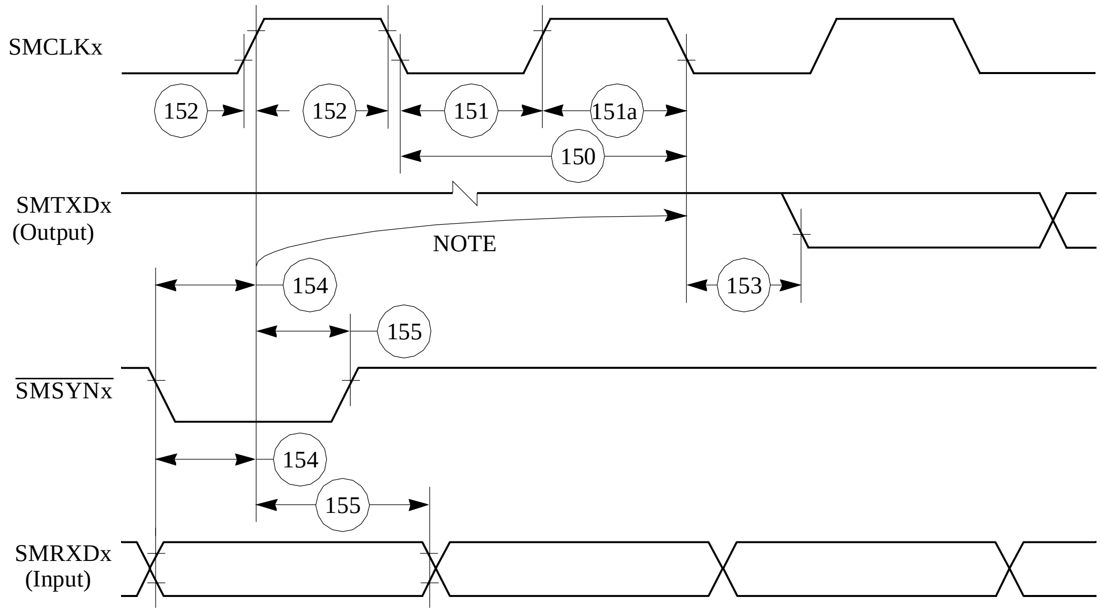
Table 19 provides the NMSI internal clock timing.

Table 19. NMSI Internal Clock Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
100	RCLKx and TCLKx frequency [1] (x = 2, 3 for all specs in this table)	0.00	SYNCCLK/3	MHz
102	RCLKx and TCLKx rise/fall time	—	—	ns
103	TXDx active delay (from TCLKx falling edge)	0.00	30.00	ns
104	$\overline{\text{RTSx}}$ active/inactive delay (from TCLKx falling edge)	0.00	30.00	ns
105	$\overline{\text{CTSx}}$ setup time to TCLKx rising edge	40.00	—	ns
106	RXDx setup time to RCLKx rising edge	40.00	—	ns
107	RXDx hold time from RCLKx rising edge [2]	0.00	—	ns
108	$\overline{\text{CDx}}$ setup time to RCLKx rising edge	40.00	—	ns

1 The ratios SyncCLK/RCLKx and SyncCLK/TCLK1x must be greater or equal to 3/1.

2 Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as an external sync signals.



NOTE:
1. This delay is equal to an integer number of character-length clocks.

Figure 56. SMC Transparent Timing Diagram

8.9 SPI Master AC Electrical Specifications

Table 22 provides the SPI master timings as shown in Figure 57 and Figure 58.

Table 22. SPI Master Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
160	MASTER cycle time	4	1024	t_{cyc}
161	MASTER clock (SCK) high or low time	2	512	t_{cyc}
162	MASTER data setup time (inputs)	50.00	—	ns
163	Master data hold time (inputs)	0.00	—	ns
164	Master data valid (after SCK edge)	—	20.00	ns
165	Master data hold time (outputs)	0.00	—	ns
166	Rise time output	—	15.00	ns
167	Fall time output	—	15.00	ns

customers that are currently using the non-JEDEC pin numbering scheme, two sets of pinouts, JEDEC and non-JEDEC, are presented in this document.

Figure 62 shows the non-JEDEC pinout of the PBGA package as viewed from the top surface.

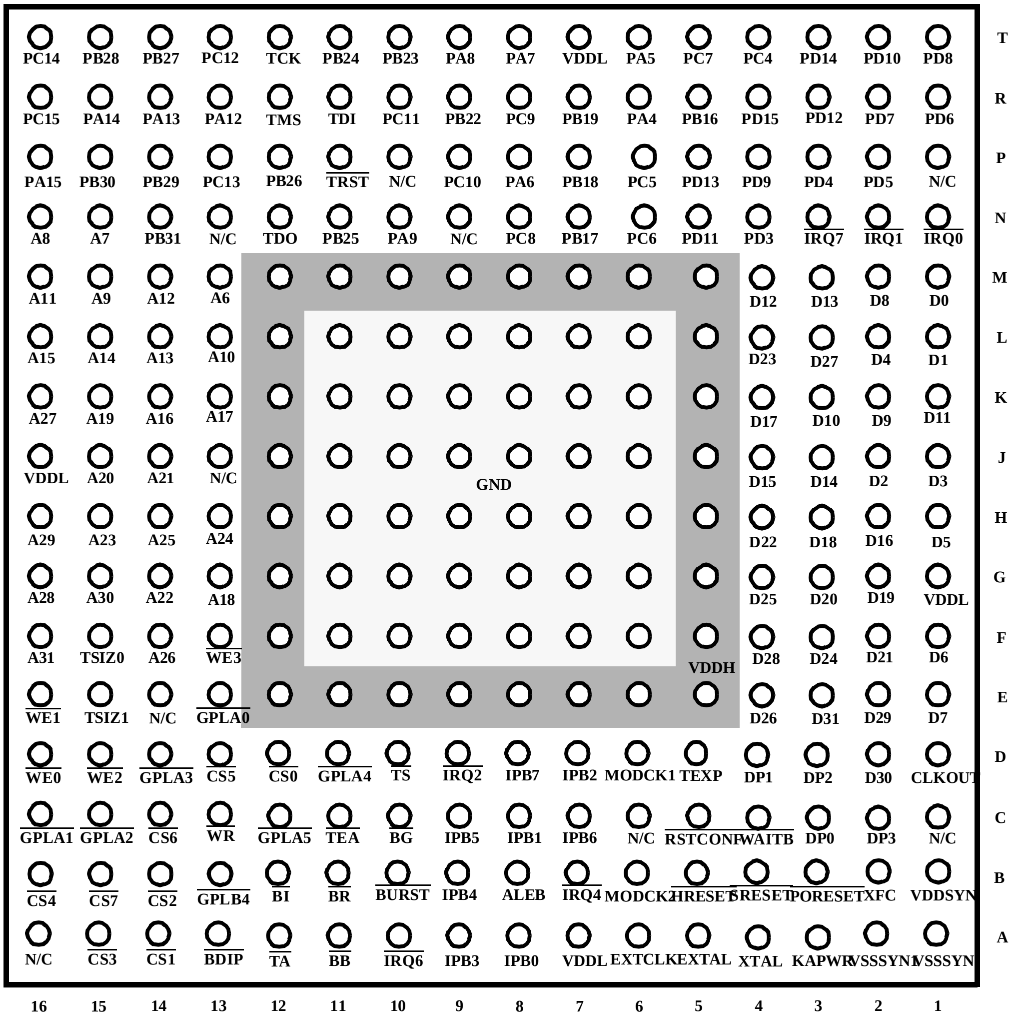


Figure 62. Pin Assignments for the PBGA (Top View)—non-JEDEC Standard

Figure 63 shows the JEDEC pinout of the PBGA package as viewed from the top surface.

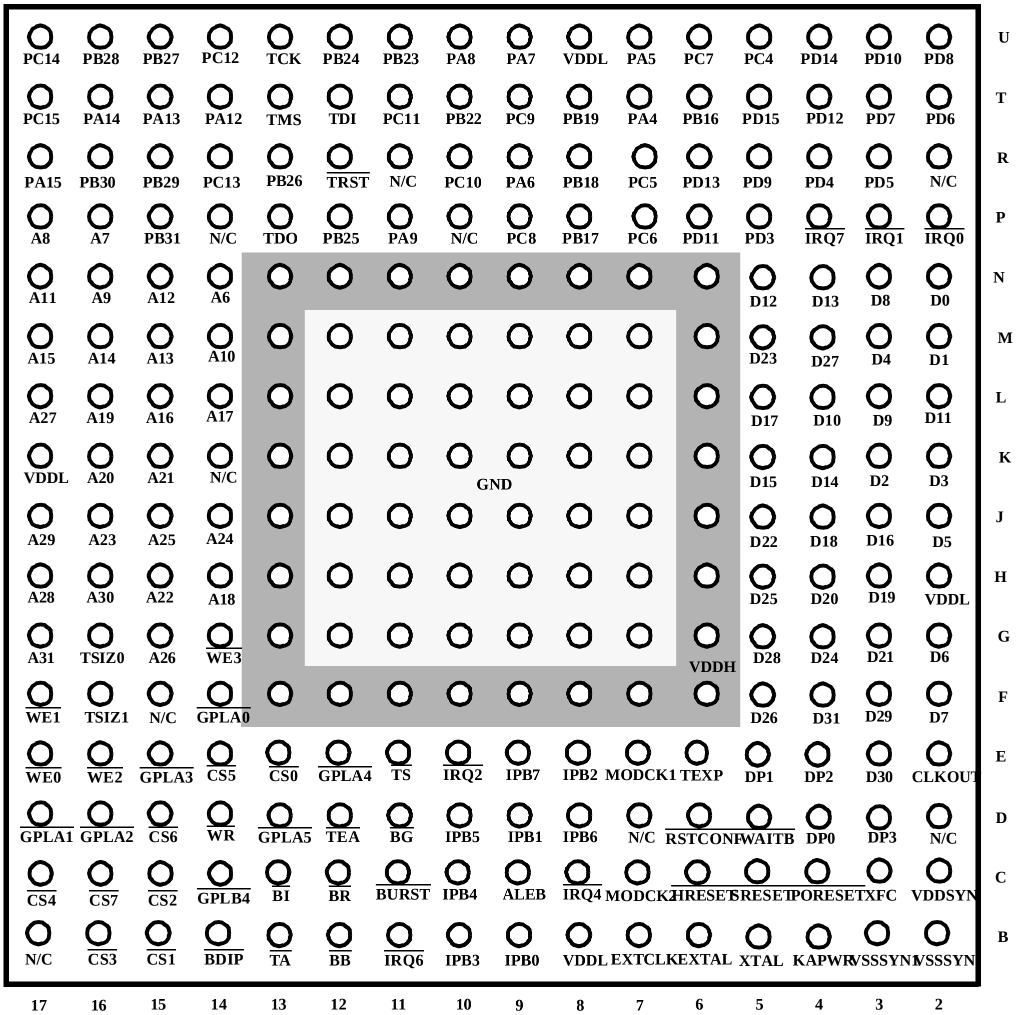
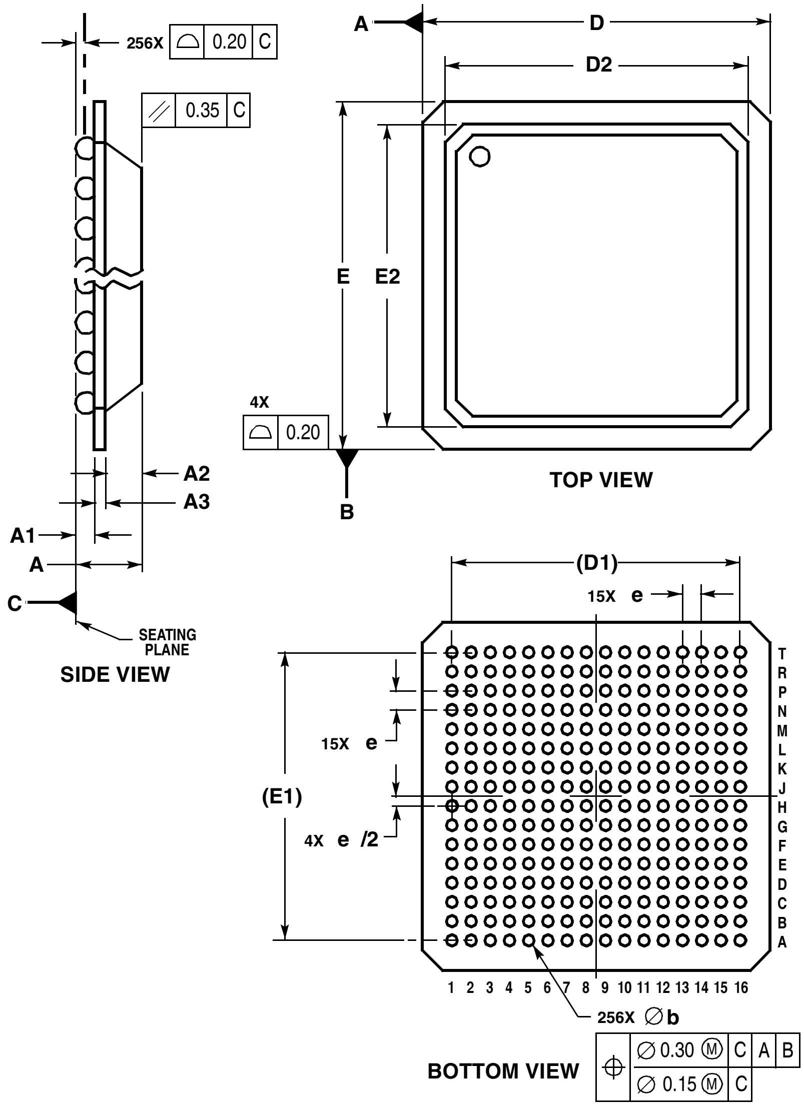


Figure 63. Pin Assignments for the PBGA (Top View)—JEDEC Standard

For more information on the printed circuit board layout of the PBGA package, including thermal via design and suggested pad layout, please refer to AN-1231/D, Plastic Ball Grid Array Application Note available from your local Freescale sales office.

Figure 64 shows the non-JEDEC package dimensions of the PBGA.



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS IN MILLIMETERS.
3. DIMENSION b IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO PRIMARY DATUM C.
4. PRIMARY DATUM C AND THE SEATING PLANE ARE

	MILLIMETERS	
DIM	MIN	MAX
A	1.91	2.35
A1	0.50	0.70
A2	1.12	1.22
A3	0.29	0.43
b	0.60	0.90
D	23.00 BSC	
D1	19.05 REF	
D2	19.00	20.00
E	23.00 BSC	
E1	19.05 REF	
E2	19.00	20.00
e	1.27 BSC	

Figure 64. Package Dimensions for the Plastic Ball Grid Array (PBGA)—non-JEDEC Standard

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Document Number: MPC850EC
Rev. 2
07/2005